



SEMIPONT® 5

Three phase antiparallel thyristor module

SKUT 85/12 V2

Features

- Compact design
- Two screws mounting
- Heat transfer and isolation through direct copper board (Low R_{th})
- Low resistance in steady-state and high reliability
- High surge currents
- Glass passivated thrysitor chips
- UL recognized, file no. E 63 532

Typical Applications*

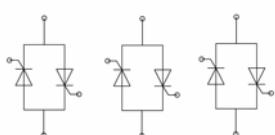
- Soft starter
- Light control (e.g. studios, theaters)
- Temperature control (e.g. oven, chemical processes)

Remarks

- $I_{RMS}=85A$, for W3C application, sin.180° and $T_s=85^\circ C$

Absolute Maximum Ratings		Values	Unit
Symbol	Conditions		
Chip			
$I_{T(AV)}$	sinus 180°	94	A
		50	A
I_{TSM}	10 ms	1150	A
		1050	A
i^2t	10 ms	6613	A^2s
		5000	A^2s
V_{RSM}		1300	V
V_{RRM}		1200	V
V_{DRM}		1200	V
$(di/dt)_{cr}$	$T_j = 130^\circ C$	50	$A/\mu s$
$(dv/dt)_{cr}$	$T_j = 130^\circ C$	500	$V/\mu s$
T_j		-40 ... 125	°C
Module			
T_{stg}		-40 ... 125	°C
V_{isol}	ac; 50Hz; r.m.s	3000	V
	1 min	3600	V
	1 s		V

Symbol	Conditions	min.	typ.	max.	Unit
Chip					
V_T	$T_j = 25^\circ C$, $I_T = 120 A$			1.8	V
$V_{T(TO)}$	$T_j = 130^\circ C$			1.1	V
r_T	$T_j = 130^\circ C$			6.00	$m\Omega$
I_{DD}, I_{RD}	$T_j = 130^\circ C$, $V_{RD}=V_{RRM}$			20	mA
t_{gd}	$T_j = 25^\circ C$, $I_G = 1 A$, $di_G/dt = 1 A/\mu s$		1		μs
t_{gr}	$V_D = 0.67 * V_{DRM}$		2		μs
t_q	$T_j = 130^\circ C$		150		μs
I_H	$T_j = 25^\circ C$			200	mA
I_L	$T_j = 25^\circ C$, $R_G = 33 \Omega$			400	mA
V_{GT}	$T_j = 25^\circ C$, d.c.	3			V
I_{GT}	$T_j = 25^\circ C$, d.c.	150			mA
V_{GD}	$T_j = 130^\circ C$, d.c.			0.25	V
I_{GD}	$T_j = 115^\circ C$, d.c.	6			mA
$R_{th(j-s)}$	continuous DC	per thyristor			K/W
$R_{th(j-s)}$		per module			K/W
$R_{th(j-s)}$		per thyristor			K/W
$R_{th(j-s)}$	sin. 180°	per module		0.43	K/W
$R_{th(j-s)}$	rec. 120°	per thyristor			K/W
$R_{th(j-s)}$		per module			K/W
Module					
$R_{th(c-s)}$					K/W
					K/W
M_s	to heatsink	2.25	2.5		Nm
M_t					Nm
a					m/s^2
w		75			g



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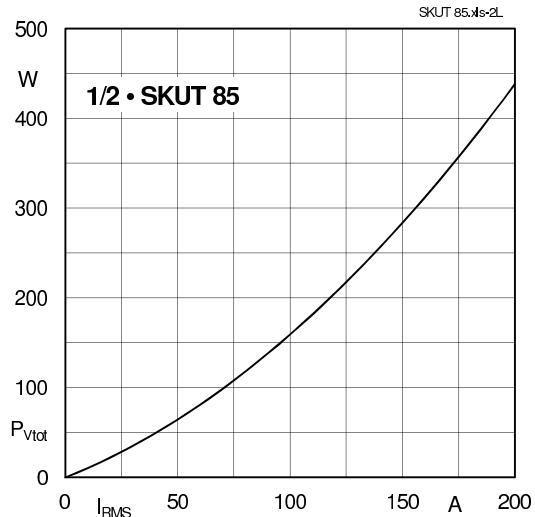


Fig. 2: Power dissipation per thyristor vs r.m.s. current

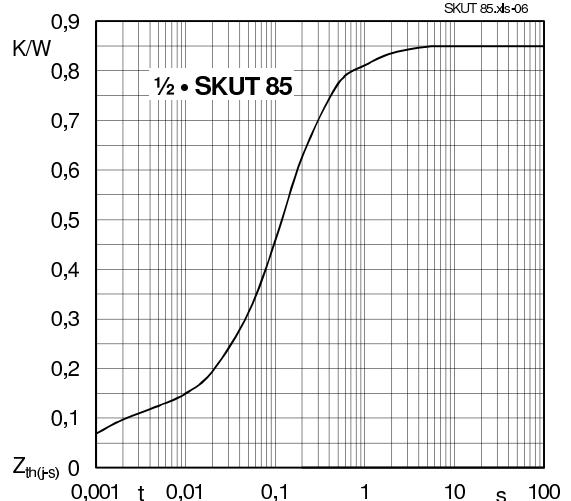


Fig. 6: Transient thermal impedance $Z_{th(j-s)}$

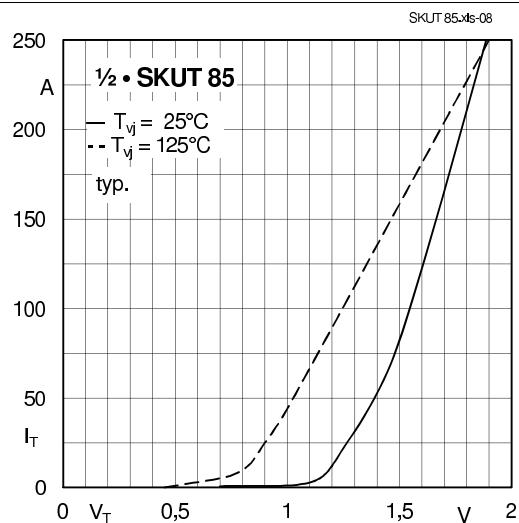


Fig. 8: On state characteristics

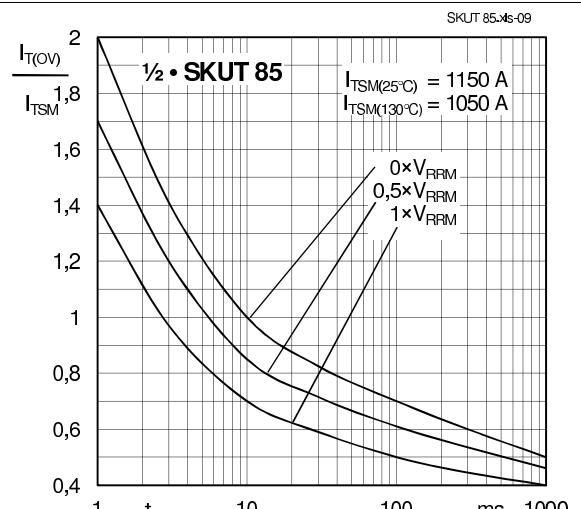


Fig. 9: Surge overload current vs. time

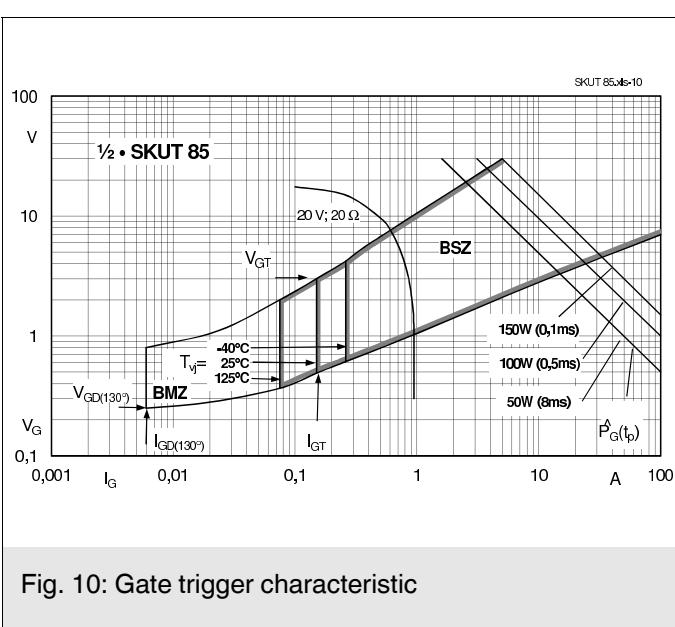
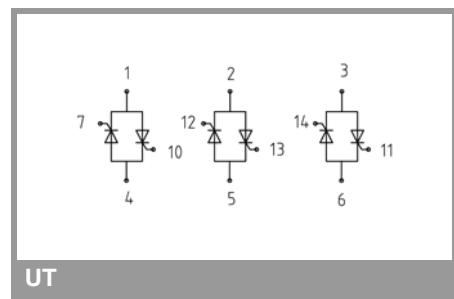
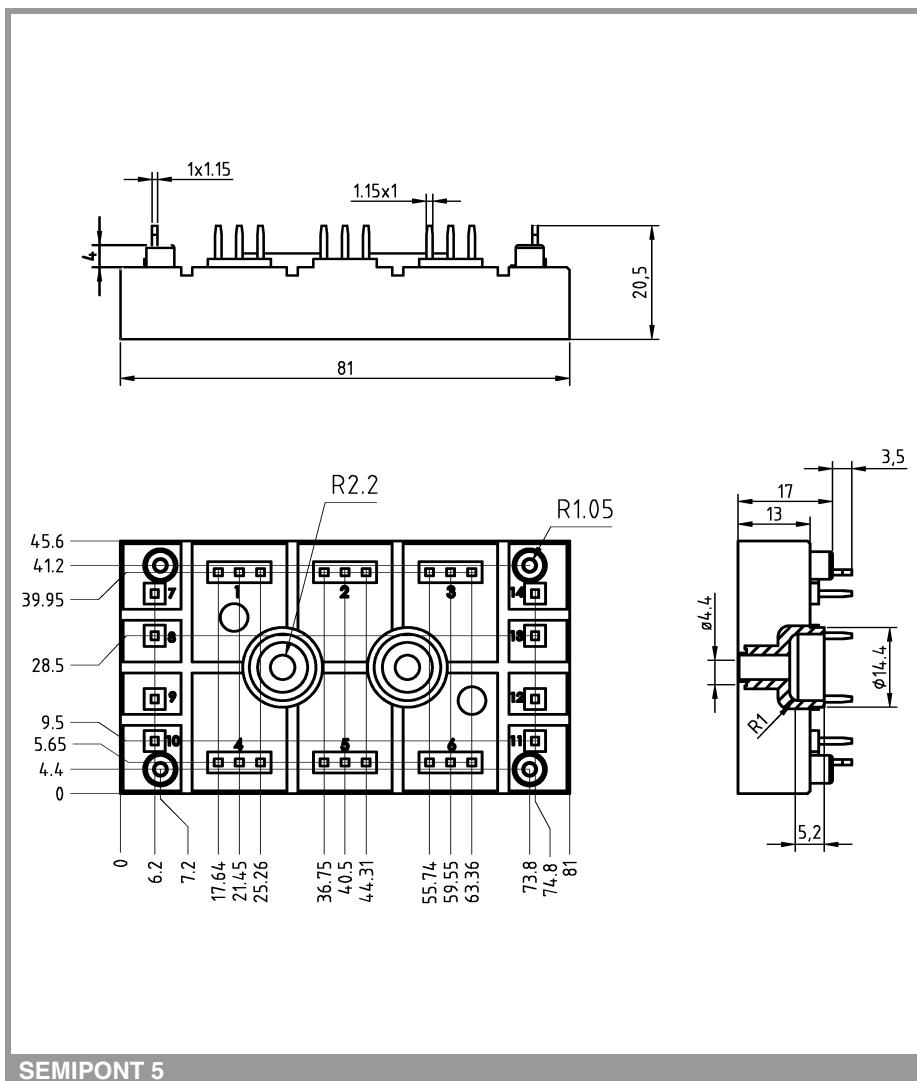


Fig. 10: Gate trigger characteristic

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